

FDR8321L

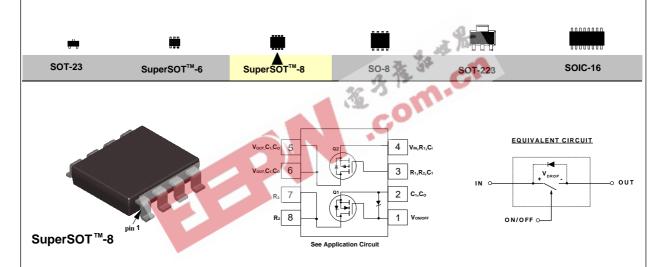
P-Channel MOSFET With Gate Driver For Load Switch Application

General Description

This device is designed for configuration as a load switch and is particularly suited for Power Management in portable battery powered electronic equipment. Designed to operate from 2.5V to 8V input and supply up to 2.9A. The device features a small N-Channel MOSFET (Q1) together with a large P-Channel power MOSFET (Q2) in a single SuperSOT $^{\text{TM}}$ -8 package.

Features

- $\begin{array}{lll} & & V_{DROP} = 0.2V \ @ \ V_{IN} = 5V, \ I_L = 2.9A. \ R_{DS(ON)} = 0.070 \ \Omega \\ & & V_{DROP} = 0.2V \ @ \ V_{IN} = 2.5V, \ I_L = 2A. \ R_{DS(ON)} = 0.105 \ \Omega. \end{array}$
- V_{ON/OFF} Zener protection for ESD ruggedness (>6KV Human Body Model).
- High density cell design for extremely low on-resistance.



Absolute Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter	FDR8321L	Units
V _{IN}	Input Voltage Range	2.5 - 8	V
V _{ON/OFF}	On/Off Voltage Range	1.5 - 8	V
I _L	Load Current @ V _{DROP} = 0.2V - Continuous (Note 1)	2.9	А
	- Pulsed	10	
P_{D}	Maximum Power Dissipation (Note 2)	0.8	W
T_J , T_{STG}	Operating and Storage Temperature Range	-55 to 150	℃
THERMA	L CHARACTERISTICS		·
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (Note 2)	156	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case (Note 2)	40	°C/W

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Electrical Characteristics (T _A = 25°C unless otherwise noted)							
Symbol	Parameter	Conditions	Min	Тур	Max	Units	
OFF CHA	RACTERISTICS	•	•		•		
I _{FL}	Forward Leakage Current	$V_{IN} = 5 \text{ V}, V_{ON/OFF} = 0 \text{ V}$			1	μΑ	
ON CHAR	ACTERISTICS (Note 3)	•					
V_{DROP}	Conduction Voltage Drop	$V_{IN} = 5 \text{ V}, \ V_{ON/OFF} = 3.3 \text{ V}, \ I_{L} = 2.9 \text{ A}$		0.185	0.2	V	
		$V_{IN} = 2.5 \text{ V}, V_{ON/OFF} = 3.3 \text{ V}, I_{L} = 2 \text{ A}$		0.18	0.2		
R _{DS(ON)}	Q ₂ - Static Drain-Source On-Resistance	$V_{GS} = -5 \text{ V}, \ I_D = -2.9 \text{ A}$		0.06	0.07	Ω	
		$V_{GS} = -2.5 \text{ V}, I_{D} = -2 \text{ A}$		0.09	0.105		
I _L	Load Current	$V_{DROP} = 0.2 \text{ V}, V_{IN} = 5 \text{ V}, V_{ON/OFF} = 3.3 \text{ V}$	2.9			Α	
		$V_{DROP} = 0.2 \text{ V}, V_{IN} = 2.5 \text{ V}, V_{ON/OFF} = 3.3 \text{ V}$	2				

- 1. V_{IN} =5V, $V_{ON/OFF}$ =8V, V_{DROP} =0.2V, T_A =25°C
- 2. R_{put} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{put} is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design. $R_{\theta JA}$ typical =156°C/W when mounted on a minimum 0.0025 in² pad on FR-4.
- 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%

逐步^{是多点}。Cn FDR8321L Load Switch Application **APPLICATION CIRCUIT** Q2 LOAD ON/OFF

External Component Recommendation

First select R2, 100 - $1k\Omega$, for Slew Rate control.

 $C1 \le 1000 pF$ can be added in addition to R2 for further In-rush current control.

Then select R1 such that R1/R2 ratio maintains between 10 - 100. R1 is required to turn Q2 off.

For SPICE simulation, users can download a "FDR8321L.MOD" Spice model from Fairchild Web Site at www.fairchildsemi.com

Typical Electrical Characteristics ($T_A = 25$ °C unless otherwise noted)

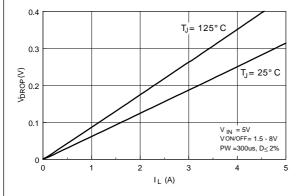


Figure 1. Conduction Voltage Drop versus
Load Current at Input Voltage 5V.

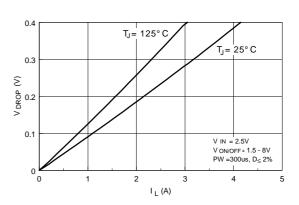


Figure 2. Conduction Voltage Drop versus Load Current at Input Voltage 2.5V.

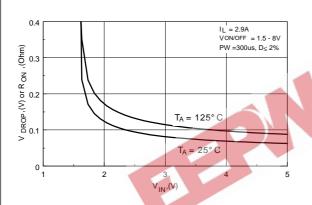


Figure 3. Conduction Voltage Drop versus input Voltage at Load Current 2.9A.

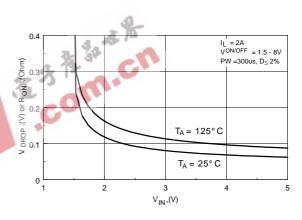


Figure 4. Conduction Voltage Drop versus Input Voltage at Load Current 2A.

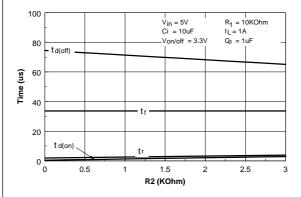


Figure 5. Switching Variation with R_2 at $V_{_{\text{in}}}\!=\!5V$ and $R_{_{1}}\!=\!10K\Omega.$

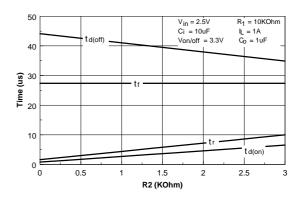


Figure 6. Switching Variation with R_2 at $V_{\rm in}{=}\,2.5V$ and $~R_1{=}\,10K\Omega.$

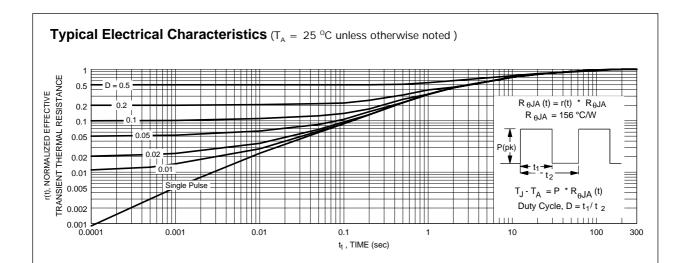
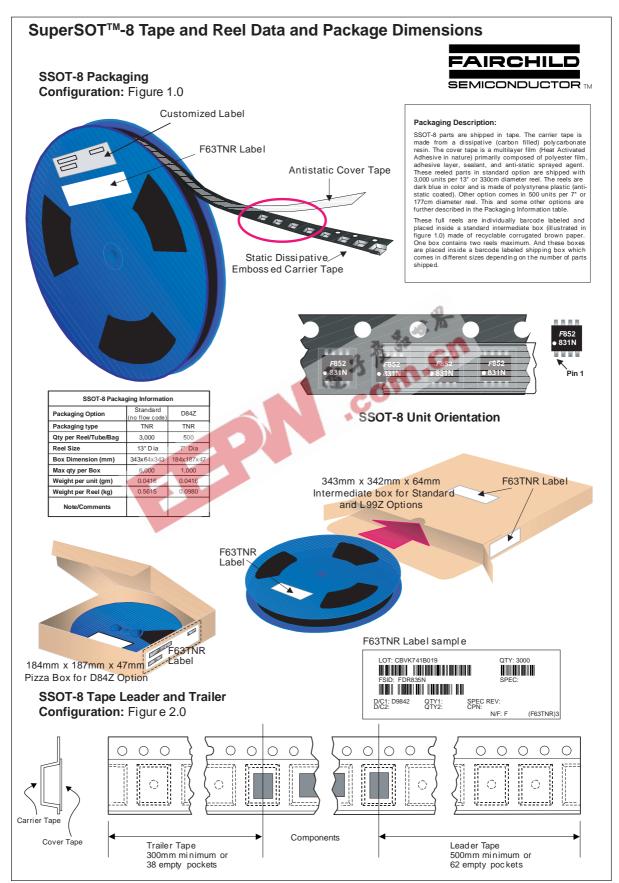
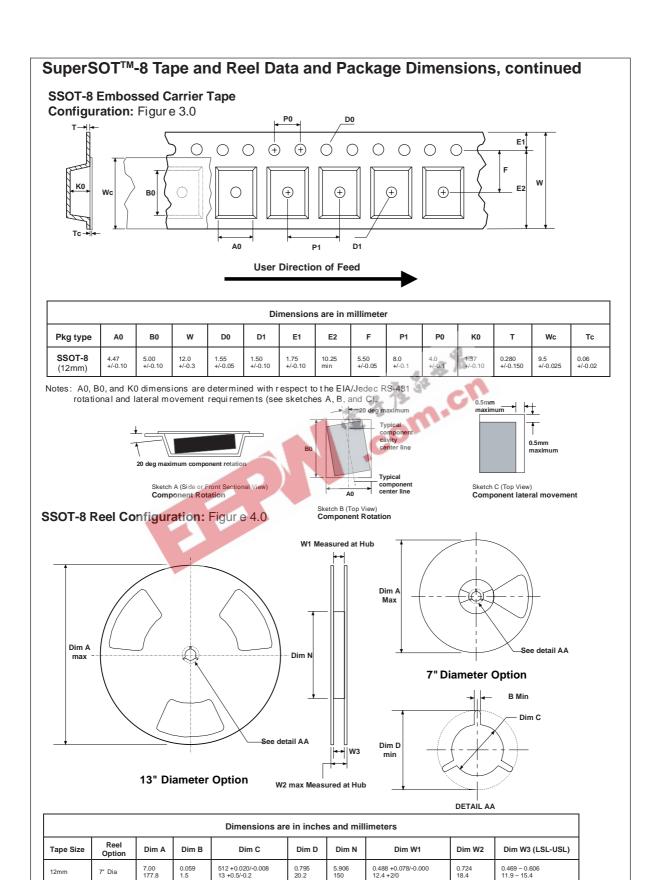


Figure 7. Transient Thermal Response Curve.

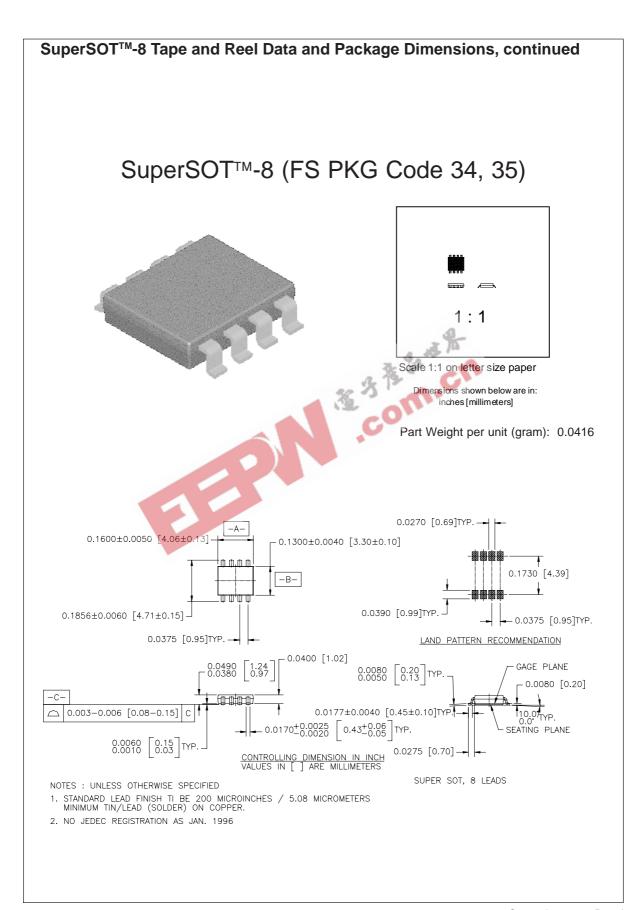






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